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DESCRIPTION

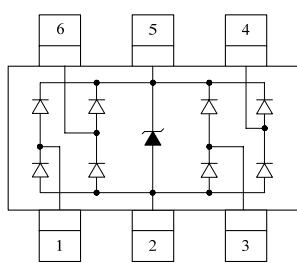
KSRV05-4MR6T1G a low capacitance of 0.4pF maximum and operates with virtually no insertion loss to 1GHz. This makes the device ideal for protection of high-speed data lines such as USB 2.0, Firewire, DVI, and gigabit Ethernet interfaces. The low capacitance array configuration allows the user to protect four high-speed data or transmission lines. The low inductance construction minimizes voltage overshoot during high current surges. They may be used to meet the ESD immunity requirements of IEC61000-4-2, Level 4 ($\pm 15\text{kV}$ air, $\pm 8\text{kV}$ contact discharge).

This device has been specifically designed to protect sensitive components which are connected to high-speed data and transmission lines from overvoltage caused by ESD (electrostatic discharge), CDE (Cable Discharge Events), and lightning.

ORDERING INFORMATION

- ◊ Device: KSRV05-4MR6T1G
- ◊ Package: SOT-23-6L
- ◊ Material: Halogen free
- ◊ Packing: Tape & Reel
- ◊ Quantity per reel: 3,000pcs

PIN CONFIGURATION



FEATURES

- ◊ Protects four I/O lines and one Vcc line
- ◊ Low capacitance
- ◊ Working voltages : 5V
- ◊ Low leakage current
- ◊ Low capacitance for high-speed interfaces
- ◊ No insertion loss to 2.0GHz
- ◊ Response Time is < 1 ns
- ◊ Solid-state silicon avalanche technology
- ◊ ROHS compliant

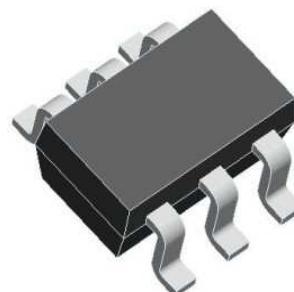
MACHANICAL DATA

- ◊ SOT-23-6L package
- ◊ Flammability Rating: UL 94V-0
- ◊ Terminal: Matte tin plated.
- ◊ Packaging: Tape and Reel
- ◊ High temperature soldering guaranteed: 260°C/10s
- ◊ Reel size: 7 inch

APPLICATIONS

- ◊ Digital Visual Interface (DVI)
- ◊ USB 1.1/2.0/OTG
- ◊ IEEE 1394 Firewire Ports
- ◊ Notebooks & Handhelds
- ◊ Projection TV & Monitors
- ◊ Set-top box
- ◊ Flat Panel Displays
- ◊ PCI Express

PACKAGE OUTLINE



ABSOLUTE MAXIMUM RATING

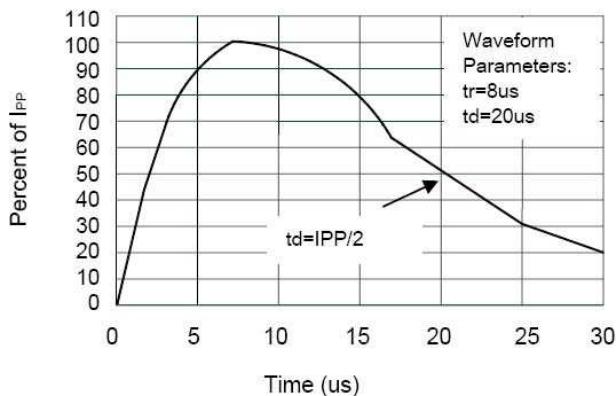
Symbol	Parameter	Value	Units
P _{PK}	Peak Pulse Power (8/20μs)	150	W
I _{PP}	Peak Pulse Current (8/20μs)	5	A
V _{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±15 ±8	kV
T _{OPT}	Operating Temperature	-55/+150	°C
T _{STG}	Storage Temperature	-55/+150	°C

ELECTRICAL CHARACTERISTICS (T_{amb}=25°C)

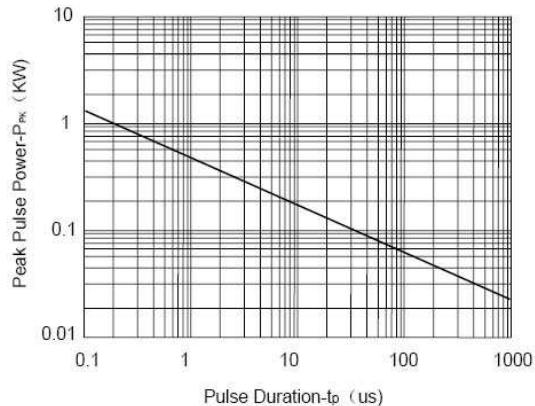
Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V _{RWM}	Reverse Working Voltage	Any I/O pin to GND			5.0	V
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA Any I/O pin to GND	6.0			V
I _R	Reverse Leakage Current	V _{RWM} = 5V Any I/O pin to GND			1	μA
V _F	Diode Forward Voltage	I _F = 15mA			1.2	V
V _{C1}	Clamping Voltage 1	I _{PP} = 1A, t _p = 8/20μs Any I/O pin to GND			15	V
V _{C2}	Clamping Voltage 2	I _{PP} = 5A, t _p = 8/20μs Any I/O pin to GND			28	V
C _{J1}	Junction Capacitance 1	V _R = 0V, f = 1MHz Between I/O pins			0.4	pF
C _{J2}	Junction Capacitance 2	V _R = 0V, f = 1MHz Any I/O pin to GND			0.8	pF

Note: I/O pins are pin 1,3,4,6.

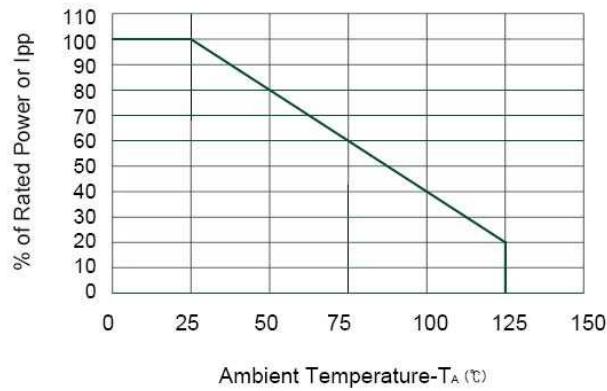
ELECTRICAL CHARACTERISTICS CURVE



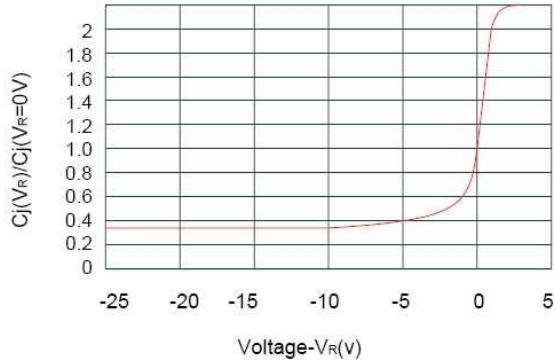
Pulse Waveform



Non-Repetitive Peak Pulse Power vs. Pulse Time

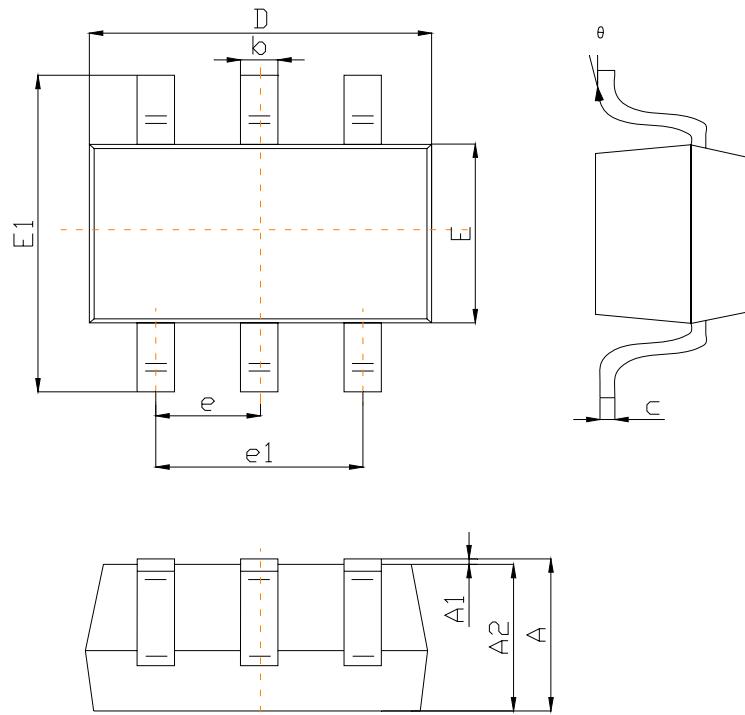


Power Derating Curve



Junction Capacitance vs. Reverse Voltage

SOT-23-6L PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100		0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
	0°	8°	0°	8°